NSN 5961-01-072-1454

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-072-1454

Inclosure Material:

Metal

Overall Length:

Between 0.325 inches and 0.460 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-61

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

25.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

voltage; junction pattern arrangement: npn

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Test Data Document:

82577-928765 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

NSN 5961-01-072-1454

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0

